- 15-V Digital or ±7.5-V Peak-to-Peak **Switching**
- 125-Ω Typical On-State Resistance for 15-V Operation
- Switch On-State Resistance Matched to Within 5  $\Omega$  Over 15-V Signal-Input Range
- **On-State Resistance Flat Over Full** Peak-to-Peak Signal Range
- High On/Off Output-Voltage Ratio: 80 dB Typical at  $f_{is} = 10 \text{ kHz}$ ,  $R_L = 1 \text{ k}\Omega$
- High Degree of Linearity: <0.5% Distortion Typical at  $f_{is} = 1 \text{ kHz}$ ,  $V_{is} = 5 \text{ V p-p}$ ,  $V_{DD} - V_{SS} \ge 10 \text{ V}, R_L = 10 \text{ k}\Omega$
- Extremely Low Off-State Switch Leakage, Resulting in Very Low Offset Current and High Effective Off-State Resistance: 10 pA Typical at  $V_{DD} - V_{SS} = 10 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$
- **Extremely High Control Input Impedance** (Control Circuit Isolated From Signal Circuit):  $10^{12} \Omega$  Typical
- Low Crosstalk Between Switches: -50 dB Typical at  $f_{is} = 8$  MHz,  $R_L = 1$  k $\Omega$

- **Matched Control-Input to Signal-Output** Capacitance: Reduces Output Signal
- Frequency Response, Switch On = 40 MHz **Typical**
- 100% Tested for Quiescent Current at 20 V
- 5-V, 10-V, and 15-V Parametric Ratings
- **Meets All Requirements of JEDEC Tentative** Standard No. 13-B, Standard Specifications for Description of "B" Series CMOS Devices
- **Applications:** 
  - Analog Signal Switching/Multiplexing: Signal Gating, Modulator, Squelch Control, Demodulator, Chopper, Commutating Switch
  - Digital Signal Switching/Multiplexing
  - Transmission-Gate Logic Implementation
  - Analog-to-Digital and Digital-to-Analog Conversion
  - Digital Control of Frequency, Impedance, Phase, and Analog-Signal Gain

#### E, F, M, NS, OR PW PACKAGE (TOP VIEW) 14 🛮 V<sub>DD</sub> SIG A IN/OUT [ SIG A OUT/IN 12 13 CONTROL A SIG B OUT/IN 3 12 CONTROL D SIG B IN/OUT I 4 11 SIG D IN/OUT CONTROL B 1 5 10 SIG D OUT/IN CONTROL C 6 9 SIG C OUT/IN 8 SIG C IN/OUT V<sub>SS</sub> [

#### description/ordering information

The CD4066B is a quad bilateral switch intended for the transmission or multiplexing of analog or digital signals. It is pin-for-pin compatible with the CD4016B, but exhibits a much lower on-state resistance. In addition, the on-state resistance is relatively constant over the full signal-input range.

The CD4066B consists of four bilateral switches, each with independent controls. Both the p and the n devices in a given switch are biased on or off simultaneously by the control signal. As shown in Figure 1, the well of the n-channel device on each switch is tied to either the input (when the switch is on) or to V<sub>SS</sub> (when the switch is off). This configuration eliminates the variation of the switch-transistor threshold voltage with input signal and, thus, keeps the on-state resistance low over the full operating-signal range.

The advantages over single-channel switches include peak input-signal voltage swings equal to the full supply voltage and more constant on-state impedance over the input-signal range. However, for sample-and-hold applications, the CD4016B is recommended.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

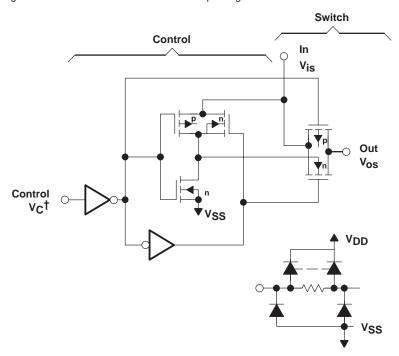


#### description/ordering information (continued)

#### **ORDERING INFORMATION**

TA	PACK	AGE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	CDIP – F	Tube of 25	CD4066BF3A	CD4066BF3A	
	PDIP – E	Tube of 25	CD4066BE	CD4066BE	
		Tube of 50	CD4066BM		
-55°C to 125°C	SOIC - M	Reel of 2500	CD4066BM96	CD4066BM	
-55 C to 125 C		Reel of 250	CD4066BMT		
	SOP - NS	Reel of 2000	CD4066BNSR	CD4066B	
	TSSOP – PW	Tube of 90	CD4066BPW	CM066B	
	1330F = FW	Reel of 2000	CD4066BPWR	CIVIOOOB	

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



<sup>&</sup>lt;sup>†</sup> All control inputs are protected by the CMOS protection network.

NOTES: A. All p substrates are connected to  $V_{\mbox{\scriptsize DD}}$ .

- B. Normal operation control-line biasing: switch on (logic 1),  $V_C = V_{DD}$ ; switch off (logic 0),  $V_C = V_{SS}$
- C. Signal-level range:  $V_{SS} \le V_{is} \le V_{DD}$

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Figure 1. Schematic Diagram of One-of-Four Identical Switches and Associated Control Circuitry



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# absolute maximum ratings over operating free-air temperature (unless otherwise noted) † DC supply-voltage range, $V_{DD}$ (voltages referenced to $V_{SS}$ terminal) ... -0.5 V to 20 V Input voltage range, $V_{is}$ (all inputs) ... -0.5 V to $V_{DD}$ + 0.5 V DC input current, $I_{IN}$ (any one input) ... ±10 mA Package thermal impedance, $\theta_{JA}$ (see Note 1): E package ... 80°C/W M package ... 86°C/W NS package ... 76°C/W PW package ... 113°C/W Lead temperature (during soldering): At distance 1/16 $\pm$ 1/32 inch (1,59 $\pm$ 0,79 mm) from case for 10 s max ... 265°C Storage temperature range, $T_{stg}$ ... -65°C to 150°C

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions

		MIN	MAX	UNIT
$V_{DD}$	Supply voltage	3	18	V
TA	Operating free-air temperature	-55	125	°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# electrical characteristics

					LIN	IITS AT II	NDICATE	D TEMPE	RATURE	S		
	PARAMETER	TEST CONDITIONS	VIN	V <sub>DD</sub>	FF00	4000	0500	40500	25	°C	UNIT	
			(V)	(V)	–55°C	-40°C	85°C	125°C	TYP	MAX		
			0, 5	5	0.25	0.25	7.5	7.5	0.01	0.25		
	Quiescent device		0, 10	10	0.5	0.5	15	15	0.01	0.5		
IDD	current		0, 15	15	1	1	30	30	0.01	1	μΑ	
			0, 20	20	5	5	150	150	0.02	5		
Signal	Inputs (Vis) and Outpu							•	ı			
		$V_C = V_{DD}$ , $R_L = 10 \text{ k}\Omega \text{ returned}$		5	800	850	1200	1300	470	1050		
ron	On-state resistance (max)	to $\frac{\left(V_{DD}-V_{SS}\right)}{2}$ ,		10	310	330	500	550	180	400	Ω	
		$V_{is} = V_{SS}$ to $V_{DD}$		15	200	210	300	320	125	240		
	On-state resistance			5					15			
$\Delta r_{on}$	difference between	$R_L = 10 \text{ k}\Omega, V_C = V_{DD}$		10					10		Ω	
	any two switches			15					5			
THD	Total harmonic distortion	$V_C = V_{DD} = 5 \text{ V}, V_{SS} = -5$ $V_{is(p-p)} = 5 \text{ V} \text{ (sine wave ce}$ $R_L = 10 \text{ k}\Omega, f_{is} = 1\text{-kHz sine}$	n 0 V),					0.4		%		
	-3-dB cutoff frequency (switch on)	$V_C = V_{DD} = 5 \text{ V}, V_{SS} = -5 \text{ V}$ (sine wave centered on 0 V	) = 5 V kΩ					40		MHz		
	-50-dB feedthrough frequency (switch off)	$V_C = V_{SS} = -5 \text{ V}, V_{is(p-p)} = (\text{sine wave centered on } 0 \text{ V})$	= 5 V ), R <sub>L</sub> = 1	kΩ					1		MHz	
I <sub>iS</sub>	Input/output leakage current (switch off) (max)	$V_C = 0 \text{ V}, V_{is} = 18 \text{ V}, V_{os} = $ and $V_C = 0 \text{ V}, V_{is} = 0 \text{ V}, V_{os} = 1 $		18	±0.1	±0.1	±1	±1	±10 <sup>-5</sup>	±0.1	μА	
	–50-dB crosstalk frequency	$\begin{array}{l} V_{C}(A) = V_{DD} = 5 \text{ V,} \\ V_{C}(B) = V_{SS} = -5 \text{ V,} \\ V_{is}(A) = 5 \text{ V}_{p\text{-}p}, 50\text{-}\Omega \text{ sourc} \\ R_{L} = 1 \text{ k}\Omega \end{array}$	ce,						8		MHz	
	Propagation delay	$R_L = 200 \text{ k}\Omega, V_C = V_{DD},$ $V_{SS} = GND, C_L = 50 \text{ pF},$		5					20	40	ns	
t <sub>pd</sub>	(signal input to signal output)	V <sub>is</sub> = 10 V (square wave centered on 5	5 V)	10					10	20		
	Signal Output)	$t_{\rm r}$ , $t_{\rm f} = 20 \text{ ns}$	,	15					7	15		
C <sub>is</sub>	Input capacitance	$V_{DD} = 5 \text{ V}, V_{C} = V_{SS} = -5$							8		pF	
Cos	Output capacitance	$V_{DD} = 5 \text{ V}, V_{C} = V_{SS} = -5$							8		pF	
C <sub>ios</sub>	Feedthrough	$V_{DD} = 5 \text{ V}, V_{C} = V_{SS} = -5$	V						0.5		pF	

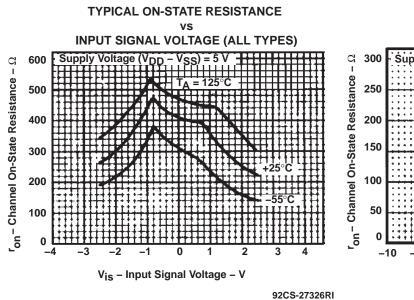


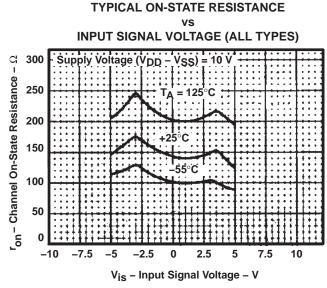
# electrical characteristics (continued)

				LIN	IITS AT II	NDICATE	D TEMPE	RATURE	S	
	CHARACTERISTIC	TEST CONDITIONS	V <sub>DD</sub>				40500	25	°C	UNIT
			(V)	−55°C	-40°C	85°C	125°C	TYP	MAX	
Contro	ol (VC)									
	Occided Second	I <sub>is</sub>   < 10 μA,	5	1	1	1	1		1	
VILC	Control input, low voltage (max)	$V_{is} = V_{SS}$ , $V_{OS} = V_{DD}$ , and	10	2	2	2	2		2	V
		$V_{iS} = V_{DD}, V_{OS} = V_{SS}$	15	2	2	2	2		2	
	Ocated Count		5			3.5 (1	MIN)			
VIHC	Control input, high voltage	See Figure 6	10		V					
	riigii voitago		15	11 (MIN)						
I <sub>IN</sub>	Input current (max)	$V_{is} \le V_{DD}$ , $V_{DD} - V_{SS} = 18 \text{ V}$ , $V_{CC} \le V_{DD} - V_{SS}$	18	±0.1	±0.1	±1	±1	±10-5	±0.1	μΑ
	Crosstalk (control input to signal output)	$V_C = 10 \text{ V (square wave)},$ $t_f$ , $t_f = 20 \text{ ns}$ , $R_L = 10 \text{ k}\Omega$	10					50		mV
			5					35	70	ns
	Turn-on and turn-off propagation delay	-  \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -   \ -	10					20	40	
	propagation delay	OL = 30 pr, KL = 1 Ks2	15					15	30	
		$V_{iS} = V_{DD}$ , $V_{SS} = GND$ , $R_L = 1 \text{ k}\Omega$ to GND, $C_L = 50 \text{ pF}$ ,	5					6		MHz
	Maximum control input repetition rate	V <sub>C</sub> = 10 V (square wave	10					9		
	-	centered on 5 V), $t_r$ , $t_f = 20$ ns, $V_{OS} = 1/2 V_{OS}$ at 1 kHz	15					9.5		
Cl	Input capacitance							5	7.5	pF

# switching characteristics

V <sub>DD</sub> (V)		SWITCH						
	V <sub>is</sub> (V)		OUTPUT, V <sub>OS</sub> (V)					
		–55°C	-40°C	25°C	85°C	125°C	MIN	MAX
5	0	0.64	0.61	0.51	0.42	0.36		0.4
5	5	-0.64	-0.61	-0.51	-0.42	-0.36	4.6	
10	0	1.6	1.5	1.3	1.1	0.9		0.5
10	10	-1.6	-1.5	-1.3	-1.1	-0.9	9.5	
15	0	4.2	4	3.4	2.8	2.4		1.5
15	15	-4.2	-4	-3.4	-2.8	-2.4	13.5	





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Figure 2

**TYPICAL ON-STATE RESISTANCE INPUT SIGNAL VOLTAGE (ALL TYPES)** 

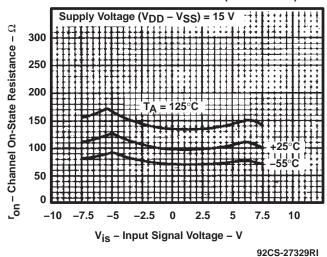


Figure 4

**TYPICAL ON-STATE RESISTANCE** 

Figure 3

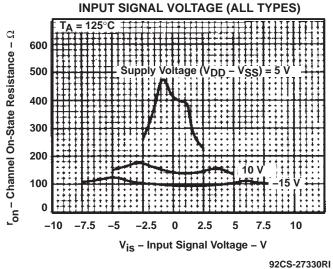
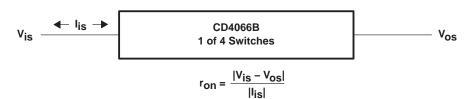


Figure 5





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Figure 6. Determination of ron as a Test Condition for Control-Input High-Voltage (VIHC) Specification

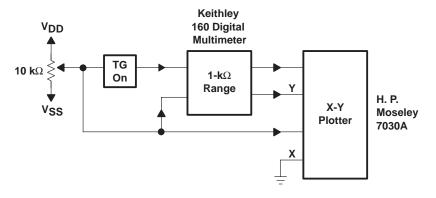
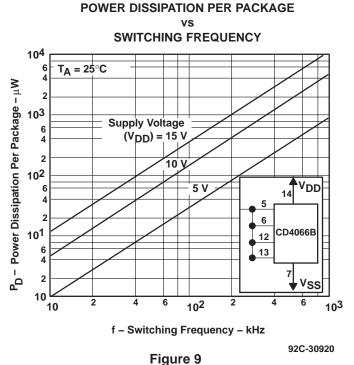
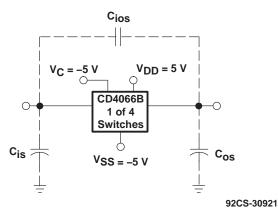


Figure 7. Channel On-State Resistance Measurement Circuit

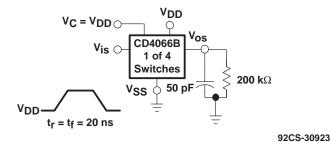
# **TYPICAL ON CHARACTERISTICS FOR 1 OF 4 CHANNELS** AMBIENT TEMPERATURE (TA) = 25°C VD0 = 2.5 V, VSS = -2.5 V ik 🛮 2 500₽ V<sub>O</sub> - Output Voltage - V 1000 $V_C = V_{DD}$ CD4066B 1 of 4 Switches ٧ss All unused terminals connected to VSS 3 V<sub>I</sub> - Input Voltage - V 92CS-30919 Figure 8





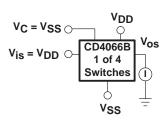
Measured on Boonton capacitance bridge, model 75a (1 MHz); test-fixture capacitance nulled out.

Figure 10. Typical On Characteristics for One of Four Channels



All unused terminals are connected to VSS.

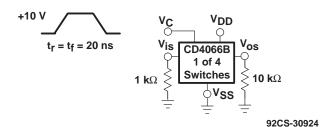
Figure 12. Propagation Delay Time Signal Input  $(V_{is})$  to Signal Output  $(V_{os})$ 



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All unused terminals are connected to VSS.

Figure 11. Off-Switch Input or Output Leakage

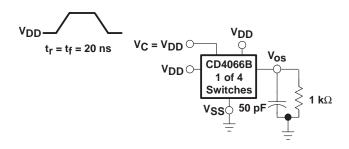


3200-0

All unused terminals are connected to VSS.

Figure 13. Crosstalk-Control Input to Signal Output



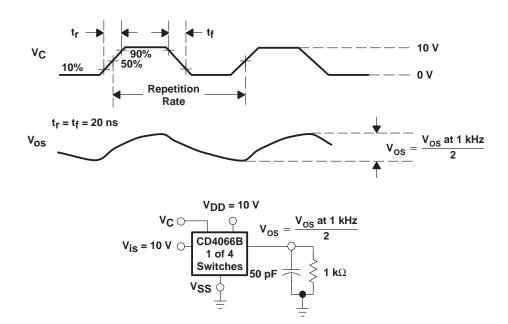


NOTES: A. All unused terminals are connected to  $V_{\mbox{SS}}$ .

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B. Delay is measured at  $V_{OS}$  level of +10% from ground (turn-on) or on-state output level (turn-off).

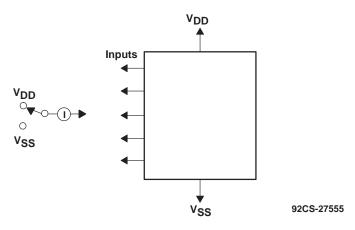
Figure 14. Propagation Delay, t<sub>PLH</sub>, t<sub>PHL</sub> Control-Signal Output



All unused terminals are connected to  $V_{SS}$ .

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Figure 15. Maximum Allowable Control-Input Repetition Rate



Measure inputs sequentially to both VDD and VSS. Connect all unused inputs to either VDD or VSS. Measure control inputs only.

Figure 16. Input Leakage-Current Test Circuit

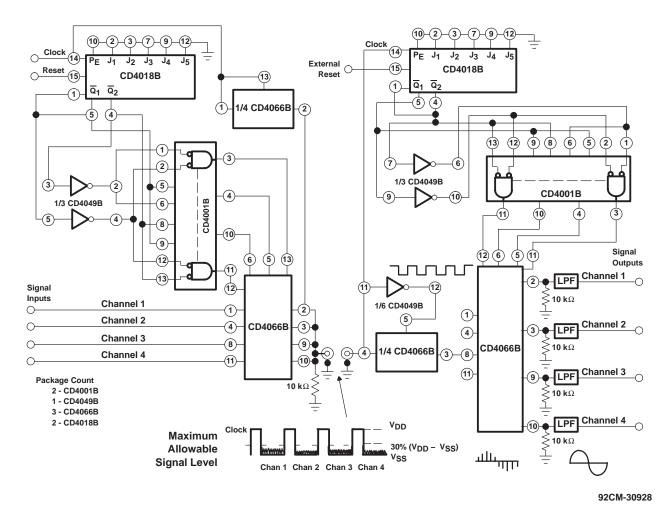
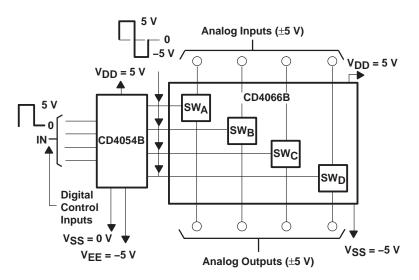


Figure 17. Four-Channel PAM Multiplex System Diagram





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Figure 18. Bidirectional Signal Transmission Via Digital Control Logic

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#### **APPLICATION INFORMATION**

In applications that employ separate power sources to drive  $V_{DD}$  and the signal inputs, the  $V_{DD}$  current capability should exceed  $V_{DD}/R_L$  ( $R_L$  = effective external load of the four CD4066B bilateral switches). This provision avoids any permanent current flow or clamp action on the  $V_{DD}$  supply when power is applied or removed from the CD4066B.

In certain applications, the external load-resistor current can include both  $V_{DD}$  and signal-line components. To avoid drawing  $V_{DD}$  current when switch current flows into terminals 1, 4, 8, or 11, the voltage drop across the bidirectional switch must not exceed 0.8 V (calculated from  $r_{on}$  values shown).

No V<sub>DD</sub> current will flow through R<sub>L</sub> if the switch current flows into terminals 2, 3, 9, or 10.







20-Sep-2015

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD4066BE	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU   CU SN	N / A for Pkg Type	-55 to 125	CD4066BE	Samples
CD4066BEE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD4066BE	Samples
CD4066BF	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD4066BF	Samples
CD4066BF3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD4066BF3A	Samples
CD4066BF3AS2283	OBSOLETE	CDIP	J	14		TBD	Call TI	Call TI			
CD4066BF3AS2534	OBSOLETE	CDIP	J	14		TBD	Call TI	Call TI			
CD4066BM	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4066BM	Samples
CD4066BM96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-55 to 125	CD4066BM	Samples
CD4066BM96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4066BM	Samples
CD4066BM96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4066BM	Samples
CD4066BME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4066BM	Samples
CD4066BMG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4066BM	Samples
CD4066BMT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4066BM	Samples
CD4066BNSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4066B	Samples
CD4066BPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM066B	Samples
CD4066BPWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM066B	Samples
CD4066BPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-55 to 125	CM066B	Samples
CD4066BPWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM066B	Samples



# PACKAGE OPTION ADDENDUM

20-Sep-2015

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
JM38510/05852BCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	(4/5) JM38510/ 05852BCA	Samples
M38510/05852BCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510/ 05852BCA	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF CD4066B, CD4066B-MIL:

• Automotive: CD4066B-Q1, CD4066B-Q1

Military: CD4066B-MIL

#### NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications

**PACKAGE MATERIALS INFORMATION** 

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# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4066BM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4066BM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4066BM96	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.3	8.0	16.0	Q1
CD4066BM96G4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4066BM96G4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4066BMT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4066BNSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4066BPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4066BM96	SOIC	D	14	2500	333.2	345.9	28.6
CD4066BM96	SOIC	D	14	2500	367.0	367.0	38.0
CD4066BM96	SOIC	D	14	2500	364.0	364.0	27.0
CD4066BM96G4	SOIC	D	14	2500	367.0	367.0	38.0
CD4066BM96G4	SOIC	D	14	2500	333.2	345.9	28.6
CD4066BMT	SOIC	D	14	250	367.0	367.0	38.0
CD4066BNSR	SO	NS	14	2000	367.0	367.0	38.0
CD4066BPWR	TSSOP	PW	14	2000	367.0	367.0	35.0

# 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



# D (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
  - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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